BD237G (NPN), BD234G, BD238G (PNP)

Plastic Medium Power Bipolar Transistors

Designed for use in 5.0 to 10 W audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

Features

- High DC Current Gain
- Epoxy Meets UL 94 V0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage BD234G DB237G, BD238G	V _{CEO}	45 80	Vdc
Collector–Base Voltage BD234G DB237G, BD238G	V _{CBO}	60 100	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current	Ι _C	2.0	Adc
Base Current	Ι _Β	1.0	Adc
Total Device Dissipation @ $T_C = 25^{\circ}C$	P _D	25	W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

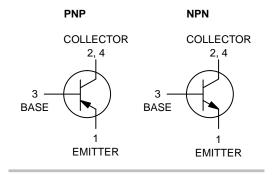
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	R_{\thetaJC}	5.0	°C/W



ON Semiconductor®

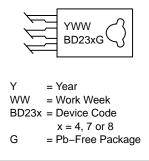
http://onsemi.com

2.0 AMPERES POWER TRANSISTORS 25 WATTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BD237G (NPN), BD234G, BD238G (PNP)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 0.1$ Adc, $I_B = 0$) BD237G, BD238G BD234G	V _{(BR)CEO}	80 45		Vdc
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ BD237G, BD238G $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ BD234G	Ісво	_	0.1	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	1.0	mAdc
DC Current Gain ($I_C = 0.15 \text{ A}, V_{CE} = 2.0 \text{ V}$) ($I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$)	h _{FE1} h _{FE2}	40 25		-
Collector–Emitter Saturation Voltage (Note 1) $(I_{C} = 1.0 \text{ Adc}, I_{B} = 0.1 \text{ Adc})$	V _{CE(sat)}	_	0.6	Vdc
Base–Emitter On Voltage (Note 1) (I _C = 1.0 Adc, V _{CE} = 2.0 Vdc)	V _{BE(on)}	_	1.3	Vdc
Current–Gain – Bandwidth Product ($I_C = 250 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$)	fT	3.0	_	MHz

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

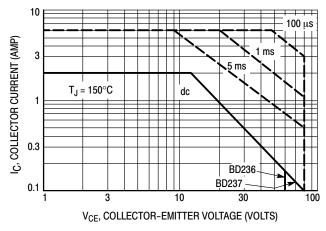
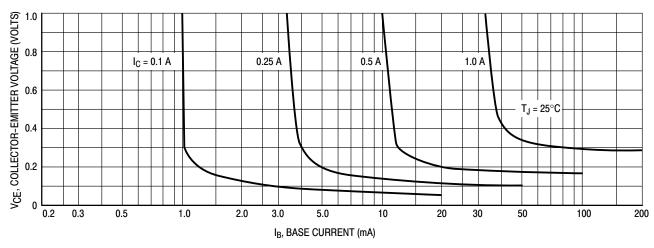


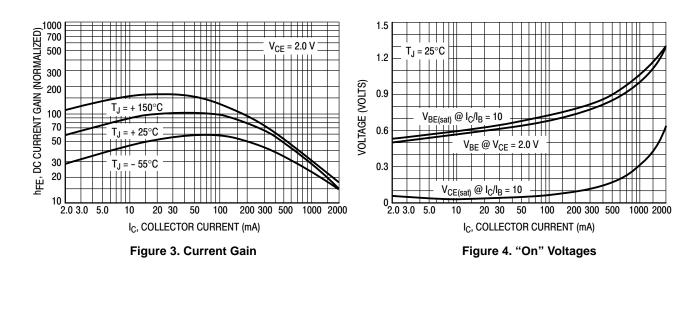
Figure 1. Active Region Safe Operating Area

The Safe Operating Area Curves indicate $I_{C-}V_{CE}$ limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power-temperature derating must be observed for both steady state and pulse power conditions.

BD237G (NPN), BD234G, BD238G (PNP)







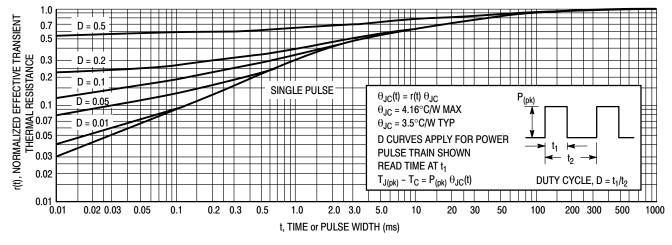


Figure 5. Thermal Response

BD237G (NPN), BD234G, BD238G (PNP)

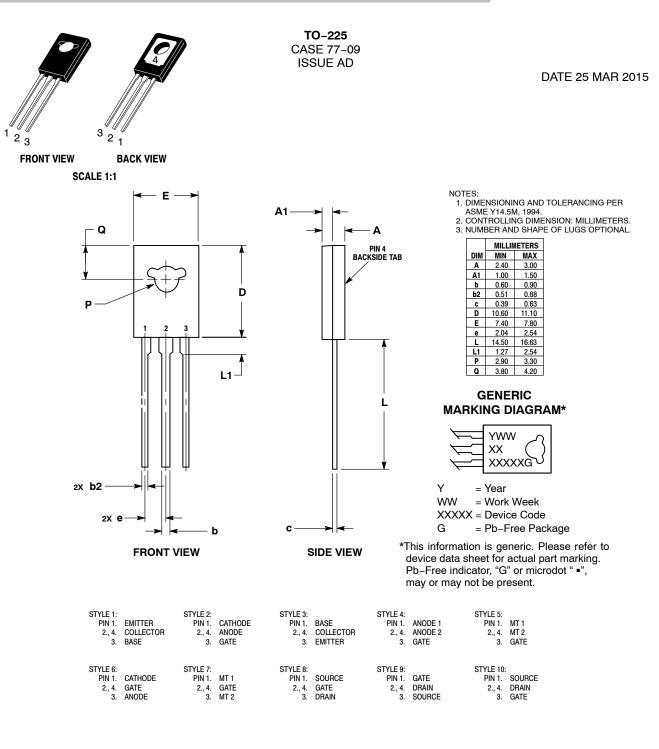
ORDERING INFORMATION

Device	Package	Shipping
BD234G	TO-225 (Pb-Free)	500 Units / Box
BD237G	TO-225 (Pb-Free)	500 Units / Box
BD238G	TO-225 (Pb-Free)	500 Units / Box

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®





DOCUMENT NUMBER:	98ASB42049B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-225		PAGE 1 OF 1	
ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.				

© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters, including "Typicals" must be validated for each customer applications by customer's technical experts. onsemi does not cust performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application or autorized for use as a critical component in life support systems or any CDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any divide for indirectly, any claim of personal injury or death associated with such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and is officers, employees, subsidiaries, and expenses, and expenses, and exponses hard snegges that onsemi was negligent regarding the design or unauthorized use ever if such claim alleges that onsemi was negligent regarding the design or manufacture of the part. onsemi is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright have and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

٥